

Errata

MSP432E4 SimpleLink™ Microcontrollers



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1 MSP432E4 SimpleLink™ Microcontrollers

1.1 Introduction

This document describes known exceptions to the functional specifications for the SimpleLink™ MSP432E4 microcontrollers. Note that some features are not available on all devices in the series, so not all errata may apply to your device. See your device-specific data sheet for more details.

For details on Arm® Cortex®-M4F CPU advisories, see the [Arm® Cortex®-M4F Errata](#).

1.2 Device Nomenclature

To designate the stages in the product development cycle, TI assigns prefixes to the part numbers of all MSP432™ MCU devices and support tools. Each MSP432 MCU commercial family member has one of two prefixes: MSP or XMS (for example, MSP432E411Y). Each support tool has one of two prefixes: MSP and MSPX. These prefixes represent evolutionary stages of product development from engineering prototypes (with XMS for devices and MSPX for tools) through fully qualified production devices and tools (with MSP for both devices and tools).

Device development evolutionary flow:

XMS – Experimental device that is not necessarily representative of the electrical specifications of the final device

MSP – Fully qualified production device

Support tool development evolutionary flow:

MSPX – Development-support product that has not yet completed TI internal qualification testing.

MSP – Fully-qualified development-support product

XMS devices and MSPX development-support tools are shipped against the following disclaimer:

"Developmental product is intended for internal evaluation purposes."

MSP devices and MSP development-support tools have been characterized fully, and the quality and reliability of the device have been demonstrated fully. TI's standard warranty applies.

Predictions show that prototype devices (XMS) have a greater failure rate than the standard production devices. TI recommends that these devices not be used in any production system because their expected end-use failure rate still is undefined. Only qualified production devices are to be used.

1.3 Device Markings

The following are examples of the microcontroller package symbolization.

MSP432E411Y, 212-pin ZAD (NFBGA) package

<pre> +-----+ \TI/ MSP432(TM) E411YT xxxxxxxxxx O REV # +-----+ </pre>	<pre> \TI/ = TI Logo (TM) = Trademark Symbol # = Die Revision O = Pin 1 </pre>
--	--

MSP432E401Y, 128-pin PDT (TQFP) package

<pre> +-----+ \TI/ xxxxxxxxxx MSP432 E401YT REV # O +-----+ </pre>	<pre> \TI/ = TI Logo # = Die Revision O = Pin 1 </pre>
--	--

1.4 Errata Overview

Table 1-1 lists the device errata.

Table 1-1. Device Errata Table

Name		Errata Title
ADC		
ADC#13		A glitch can occur on pin PE3 when using any ADC analog input channel to sample
ADC#14		The first two ADC samples may be incorrect
EPI		
EPI#01		Data reads can be corrupted when the code address space in the EPI module is used
GPIO		
GPIO#09		In some cases, noise injected into GPIO pins PB0 and PB1 can cause high current draw
General-Purpose Timers		
GPTM#09		General-purpose timers do not synchronize when configured for RTC mode
GPTM#15		Counter does not immediately clear to 0 when MATCH is reached in edge count up mode
Hibernation		
HIB#10		If MEMCLR is set to a nonzero value, a tamper event may not clear all of the bits in the HIBDATA register
HIB#16		Application code may miss new tamper event during clear
HIB#18		Can get two matches per day in calendar mode
HIB#19		The first write to the HIBCTL register may not complete successfully after a Hibernation module reset
Memory		
MEM#07		Soft resets should not be asserted during EEPROM operations
MEM#15		Specific flash locations in any sector do not get erased
MEM#16		JTAG unlock issue when BOOTCFG is committed with NW=0
PWM		
PWM#04		PWM generator interrupts can only be cleared 1 PWM clock cycle after the interrupt occurs
PWM#05		Generator load with global sync may lead to erroneous pulse width
PWM#06		PWM output may generate a continuous high instead of a low or a continuous low instead of high
QEI		
QEI#01		When using the index pulse to reset the counter, a specific initial condition in the QEI module causes the direction for the first count to be misread
SSI		
SSI#03		SSI1 can only be used in legacy mode
SSI#05		Bus contention in bi- and quad-mode of SSI
SSI#06		SSI receive FIFO time-out interrupt may assert sooner than expected in slave mode
SSI#07		SSI transmit interrupt status bit is not latched
SSI#08		SSI slave in bi and quad mode swaps XDAT0 and XDAT1
System Control		
SYSCTL#03		The MOSC verification circuit does not detect a loss of clock after the clock has been successfully operating
SYSCTL#18		DIVSCLK outputs a different clock frequency than expected when DIV = 0x0
SYSCTL#24		Modules may not be ready for access if their power domains are first turned off and then on
USB		
USB#04		Device sends SE0 in response to a USB bus reset
Watchdog Timers		
WDT#08		Reading the WDTVALUE register may return incorrect values when using Watchdog Timer 1

1.5 Errata Descriptions

ADC#13 *A glitch can occur on pin PE3 when using any ADC analog input channel to sample*

Description

A glitch may occur on PE3 when using any ADC analog input channel (AINx) to sample. This glitch can occur when PE3 is configured as an input channel and happens at the end of the ADC conversion. These glitches do not affect analog measurements on PE3 when configured as AIN0 as long as the specified source resistance is met.

Workaround

A 1-kΩ external pullup or pulldown on PE3 helps to minimize the magnitude of the glitch to 200 mV or less.

ADC#14 *The First two ADC Samples may be Incorrect*

Description

The first two ADC samples taken after the ADC clock is enabled in the xCGCADC register may be incorrect.

Workaround

1. Reset the ADC peripheral using the SRADC register after the ADC peripheral clock is enabled and before initializing the ADC and enabling the sample sequencer.
2. If reconfiguration cannot be done by the application, then discard the first two samples before processing the data.

EPI#01 *Data reads can be corrupted when the code address space in the EPI module is used*

Description

The external code address space at address 0x1000.0000 is specified for the EPI module using the ECSZ and ECADR fields in the EPI Address Map (EPIADDRMAP). However, data reads can be corrupted when using this address space.

Workaround

Code cannot be executed from the 0x1000.0000 address space. The EPI address spaces at 0x6000.0000 and 0x8000.0000 can be used instead.

In addition, when reading from EPI memory mapped to the code address space at 0x1000.0000, replace direct EPI memory reads through pointers with calls to the EPIWorkaroundWordRead(), EPIWorkaroundHWordRead() or EPIWorkaroundByteRead() functions depending on the data size for the read operation. Similarly, when writing to the EPI code address space, replace direct writes with calls to the EPIWorkaroundWordWrite(), EPIWorkaroundHWordWrite() or EPIWorkaroundByteWrite() functions. These APIs are new and can be found in [Section 1.7](#). For Keil, IAR, GCC, and Code Bench, these functions are defined as inline functions in the epi.h file in the *driverlib* folder. For CCS, which doesn't support this structure, these should be added to a new file placed in the *driverlib* directory called epi_workaround_ccs.s, and this file should be added to the project. Note that the new DriverLib APIs and the CCS file mentioned in [Section 1.7](#) are included in the SimpleLink MSP432 SDK.

GPIO#09	<i>In some cases, noise injected into GPIO pins PB0 and PB1 can cause high current draw</i>
Description	<p>A fast transition on either PB0 or PB1 can switch on a low resistance path between one or both pins and ground potentially causing a high current draw.</p> <p>This condition has been observed when the signal at the device pin has a rise time or fall time (measured from 10% to 90% of VDD) that is faster than 2 ns. The condition is more likely to occur at high temperatures or in noisy environments. It can occur when the pin is in input or output mode or with any pin multiplexing options.</p> <p>If the condition is induced while the pin is configured as an output GPIO, then changing the pin state to low and then returning it to a high state at a lower temperature will resolve the condition.</p>
Workaround	<ol style="list-style-type: none"> 1. Do not use PB0 and PB1. Connect both to GND through a 1-kΩ resistor and configure them as GPIO inputs. 2. If PB0 and PB1 are used as USB0ID and USB0VBUS, see the USB section of System Design Guidelines for MSP432E4 Microcontrollers and confirm all guidelines contained in the document are followed.
GPTM#09	<i>General-purpose timers do not synchronize when configured for RTC mode</i>
Description	<p>When attempting to synchronize the General-Purpose Timers using the GPTM Synchronize (GPTMSYNC) register, they do not synchronize if any of the timers are configured for RTC mode.</p>
Workaround	None.
GPTM#15	<i>Counter does not immediately reset to 0 when MATCH is reached in edge count up mode</i>
Description	<p>When configured for input edge count mode and count up mode, after counting to the match value, the counter uses one additional edge to reset the timer to 0. As a result, after the first match event, all subsequent match events occur after the programmed number of edge events plus one.</p>
Workaround	In software, account for one additional edge in the programmed edge count after the first match interrupt is received.
HIB#10	<i>If MEMCLR is set to a nonzero value, a tamper event may not clear all of the bits in the HIBDATA register</i>
Description	<p>If the MEMCLR bit field in the HIB Tamper Control (HIBTPCTL) register is set to a non-zero value, the Hibernation Data (HIBDATA) register may not clear the specified bits. The MEMCLR bit field provides the option to clear all, the upper half, lower half, or none of the Hibernation memory on a tamper event.</p>

HIB#10 (continued) *If MEMCLR is set to a nonzero value, a tamper event may not clear all of the bits in the HIBDATA register*

Workaround

After clearing the tamper event by setting the TPCLR bit, the application should clear the data in the Hibernate memory in the HIBDATA register (write either the upper half, the lower half, or all of the bits to all zeros).

HIB#16 *Application code may miss new tamper event during clear*

Description

During the clear of a tamper event, a new tamper event could be missed or the tamper log could be corrupted. The clear of a tamper event starts with the Tamper Clear (TPCLR) bit in the HIB Tamper Control register (HIBTPCTL) being written. The write takes 3 rising edges of the 32.768-kHz clock to complete the clear.

Workaround

To prevent missing a tamper event during these three Hibernate clock cycles and restoring the tamper log to its reset state, workaround code must be implemented in the NMI handler as shown in [Section 1.6](#). The new DriverLib APIs mentioned in [Section 1.6](#) are included in the SimpleLink MSP432E4 SDK.

HIB#18 *Can get two matches per day in calendar mode*

Description

When the CAL24 bit in the Hibernation Calendar Control (HIBCALCTL) register is clear, the RTC counts in 12 hour, AM/PM mode. The AM/PM bit in the Hibernation Calendar Match 0 (HIBCALM0) specifies whether the match should occur in the AM or the PM. However, this bit is ignored when determining if a match is occurring. As a result, an RTC match could occur twice in one day.

Workaround

Adjust the match time to 24 hour mode before configuring the HIBCALM0 register and set the CAL24 bit. Alternatively, when the match occurs, check the AM/PM bit in the Hibernation Calendar (HICAL0) register to determine if the match is correct.

HIB#19 *The first write to the HIBCTL register may not complete successfully after a Hibernation module reset*

Description

The initial write to the HIBCTL register may not occur if the Hibernation module is reset. The WRC bit in the HIBCTL register may not be set.

Workaround

After a Hibernation module reset, check to see if the WRC bit is set and perform the following:

- If the WRC bit is not set within the maximum oscillator startup time, perform a software reset of the Hibernation module and retry the HIBCTL write. The maximum oscillator startup time is given by the Hibernation XOSC startup time parameter, TSTART, in the Hibernation External Oscillator (XOSC) Input Characteristics table in the Electrical Characteristics chapter of the data sheet.
- If the WRC bit is set but the HIBCTL write was not successful, retry the HIBCTL write.

MEM#07
Soft resets should not be asserted during EEPROM operations
Description

EEPROM data may be corrupted if any of the following soft resets are asserted during an EEPROM program or erase operation:

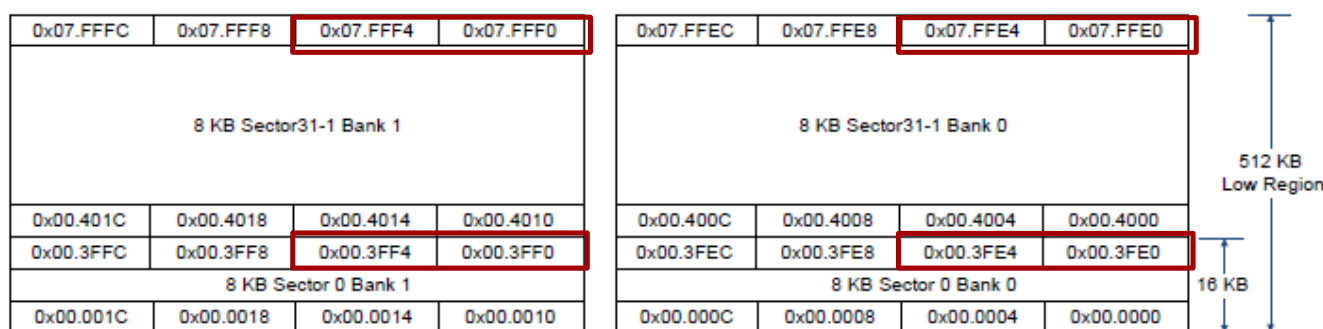
- Software reset (SYSRESREQ)
- Software peripheral reset of the EEPROM module
- Watchdog reset (if configured as a system reset in the RESBEHAVCTL register)
- MOSC failure reset
- BOR reset (if configured as a system reset in the RESBEHAVCTL register)
- External reset (if configured as a system reset in the RESBEHAVCTL register)
- Writes to the HSSR register

Workaround

Ensure that any of the above soft resets are not asserted during an EEPROM program or erase operation. The WORKING bit of the EEDONE register can be checked before the reset is asserted to see if an EEPROM program or erase operation is occurring. Soft resets may occur when using a debugger and should be avoided during an EEPROM operation. A reset such as the Watchdog reset can be mapped to an external reset using a GPIO or Hibernate can be entered, if time is not a concern.

MEM#15
Specific flash locations in any sector do not get erased
Description

If only one or both of the first two words of the last line of a sector in a bank are programmed, an Erase of entire Sector, Mass Erase of device, or toggle mass erase does not erase the flash back to all 1's. The diagram below shows the affected words in Sector 0 and Sector 31 of the lower 512KB of Flash.


Workaround

Program any other word in the Sector-Bank to allow Sector Erase to work.

Note

Toggle Mass Erase or Mass Erase will still not work.

MEM#16
JTAG unlock issue when BOOTCFG is committed with NW=0
Description

After configuring the BOOTCFG register with NW=0, DBG1=0 and DBG=1, the JTAG Debugger access is locked and cannot be unlocked by one Unlock Sequence Run.

Workaround

The Unlock Sequence has to be run twice for the device to be unlocked.

PWM#04	<i>PWM generator interrupts can only be cleared 1 PWM clock cycle after the interrupt occurs</i>
Description	A write of 1 to the PWMxISC register is expected to clear the corresponding generator interrupt status on the next system clock. However, the write will clear the generator interrupt status on the next PWM clock. Any write to the PWMxISC to clear the interrupt before the next PWM clock will be ignored and the interrupt will be re-asserted.
Workaround	After the interrupt is asserted, the CPU must wait for one PWM clock cycle before writing 1 to the PWMxISC to clear the corresponding generator interrupt status. The larger the PWM clock divider value, the longer the system delay to clear the interrupt.
PWM#05	<i>Generator load with global sync may lead to erroneous pulse width</i>
Description	There is a condition where the generator timer may still count with the old value, but the new comparator value gets loaded causing an erroneous high pulse width.
Workaround	The application must use the interrupt status to write the value of the new load and comparator values. When using the down count mode, clear the raw interrupt status bit for the respective comparator down count match interrupt status bit, wait for it to be set again and then update the new value for the load and comparator match.
PWM#06	<i>PWM output may generate a continuous high instead of a low or a continuous low instead of high</i>
Description	<p>When using PWM in UP-DOWN count mode, the PWM generator may generate a continuous High instead of Low or continuous Low instead of High under the following condition:</p> <ul style="list-style-type: none"> • The PWM generator is used with action for comparator A or B UP and DOWN to control the PWM cycle. • The PWM comparator A or B is changed from a count of 2 or more to PWM Load Count value. • A continuous High is generated if the invert option is enabled. • A continuous Low is generated if the invert option is disabled.
Workaround	<ul style="list-style-type: none"> • Use DOWN count mode of PWM • When changing from any value (other than 1) to the PWM load count value in the Comparator Load Register, always go to value of 1 before going to the PWM load count value.
QE#01	<i>When using the index pulse to reset the counter, a specific initial condition in the QE1 module causes the direction for the first count to be misread</i>
Description	<p>When using the index pulse to reset the counter with the following configuration in the QE1 Control (QE1CTL) register:</p> <ul style="list-style-type: none"> • SIGMODE is 0 indicating quadrature mode • CAPMODE is 1 indicating both PhA and PhB edges are counted <p>and the following initial conditions:</p>

QEI#01 (continued) *When using the index pulse to reset the counter, a specific initial condition in the QEI module causes the direction for the first count to be misread*

- Both PhA and PhB are 0
- The next quadrature state is in the counterclockwise direction

the QEI interprets the state change as an update in the clockwise direction, which results in a position mismatch of 2.

Workaround

None.

SSI#03 *SSI1 can only be used in legacy mode*

Description

Bi-, quad-, and advance-modes of operation do not function correctly on the specified SSI module(s). As a result, any affected module can only be used for legacy operation.

Workaround

Use SSI0, SSI2, or SSI3 for bi-, quad-, and advance-mode operation. Use SSI1 for legacy-mode operation.

SSI#05 *Bus contention in bi- and quad-mode of SSI*

Description

When the SSI is configured in Bi- or Quad-mode, and a read from external memory is performed after the SSI is configured for Receive Mode, bus contention can occur on the SSI data pins on that first data read.

Workaround

Perform a dummy read from memory before the first valid read operation after configuring the SSI for Receive Mode (setting the DIR bit in the QSSI Control (SSICR1) register). For example:

```

SSIConfigSetExpClk(SSIO_BASE, SysCtlClockFreqSet (),
SSIFRF_MOTO_MODE_0, SSI_MODE_MASTER, 1000000, 8);
SSIAdvModeSet(SSIO_BASE, SSI_ADV_BI_READ); //Receive Mode set
SSIDataPut(SSIO_BASE, &ui32DataRx[ui32Index]); //intentional dummy write
SSIDataGetNonBlocking(SSIO_BASE, ui32Dummy); //dummy read
SSIDataPut(SSIO_BASE, &ui32DataRx[ui32Index]); //intentional dummy write
SSIDataGetNonBlocking(SSIO_BASE, &ui32DataRx[0])); //first intentional
read
SSIDataPut(SSIO_BASE, &ui32DataRx[ui32Index]); //intentional dummy write
SSIDataGetNonBlocking(SSIO_BASE, &ui32DataRx[1])); //second intentional
read

```

If the transfer normally requires any dummy operations, such as the intentional dummy writes shown above, the dummy read should occur before the normal dummy operations.

Note that if your application is sensitive to the SSIClk, the dummy read outputs a clock cycle. Reconfigure the SSIClk pin to a GPIO input while performing the dummy read to prevent this from affecting your clock-sensitive application.

SSI#06 *SSI receive FIFO time-out interrupt may assert sooner than expected in slave mode*

Description

The SSI receive FIFO time-out interrupt may assert sooner than 32 system clock periods in slave mode if the CPSDVSR field in the SSI Clock Prescale (SSICPSR) register is set to a value greater than 0x2. Master mode is not affected by this behavior.

SSI#06 (continued) *SSI receive FIFO time-out interrupt may assert sooner than expected in slave mode*

Workaround

In some cases, software can use the SCR field in the SSI Control 0 (SSICR0) register in combination with a CPSDVSR field value of 0x2 to attain the same SSI clock frequency. For example, if the desired serial clock rate is SysClk/48, then CPSDVSR = 0x2 and SCR = 0x17 can be used instead of CPSDVSR = 0x18 and SCR = 0x1 to achieve the same clock rate, using the equation $SSInCLK = SysClk / (CPSDVSR * (1 + SCR))$. If there is not a value of SCR that can be used with CPSDVSR = 0x2 to attain the required serial clock rate, then the receive FIFO time-out feature cannot be used.

SSI#07 *SSI transmit interrupt status bit is not latched*

Description

SSI Transmit Interrupt Status Bit does not work correctly.

- For Master Mode with interrupts when transmit FIFO is half full or less. SSIMIS will be asserted every time the TXFIFO drops below half FIFO threshold causing the interrupt to be asserted all the time even if SSICR register is used to clear the Interrupt condition

Workaround

In the interrupt handler on completion of the transfer from the buffer to SSIDR clear the SSIM.TXIM to stop any further interrupts. When the next set of interrupts are required for transmission then set the SSIM.TXIM bit.

SSI#08 *SSI slave in bi and quad mode swaps XDAT0 and XDAT1*

Description

The SSI Slave when in Bi or Quad Mode sends the data on XDAT0 to XDAT1 line and XDAT1 to XDAT0 line.

Workaround

When transmitting the data from SSI Slave in Bi and Quad Mode the CPU must swap the bits when writing to the Data Register SSIDR for the correct bit to be transmitted. When using uDMA CPU must write the swapped bits in the uDMA's source buffer.

SYCTL#03 *The MOSC verification circuit does not detect a loss of clock after the clock has been successfully operating*

Description

If the MOSC clock source has been powered up and operating correctly and is subsequently removed or flatlines, the MOSC verification circuit does not indicate an error condition.

Workaround

Use Watchdog module 1, which runs off of PIOSC, to reset the system if the MOSC fails.

SYCTL#18 *DIVSCLK Outputs a Different Clock Frequency than Expected when DIV = 0x0*

Description

In the Divisor and Source Clock Configuration (DIVSCLK) register, if the DIV bit field is 0x0 (divided by 1), the clock output to the GPIO is not what is expected:

- If the DIV bit field has not yet been adjusted in code, the clock frequency will be the clock source defined in the SRC bit field divided by 32. For example, if SRC = 0x1 (PIOSC) and DIV = 0x0, the clock output to the GPIO will have a frequency of 500 kHz, derived from the PIOSC.

SYSTCTL#18
(continued)

DIVSCLK Outputs a Different Clock Frequency than Expected when DIV = 0x0

- If the DIV bit field has already been adjusted in code, the clock frequency will be the clock source defined in the SRC bit field divided by the previous DIV bit field value. For example, if SRC = 0x1 (PIOSC) and DIV was previously 0x1 (divided by 2) then written to 0x0, the clock output to the GPIO will have a frequency of 8 MHz, derived from the PIOSC.

Workaround

If clock accuracy of the source is not a factor, certain frequencies can be achieved using a non-zero DIV value and a different SRC value. For example, to achieve a 16 MHz clock, instead of SRC = 0x1 (PIOSC) and DIV = 0x0, use SRC = 0x0 (System Clock) and the respective DIV value (DIV = 0x4 (divided by 5) for a system clock of 80 MHz).

SYSTCTL#24
Modules may not be ready for access if their power domains are first turned off and then on

Description

There are five modules (CAN, Ethernet MAC, Ethernet PHY, USB and CCM) on the device that reside in a separate power domain. These modules can be turned off of their power domains to save additional leakage currents. When the power domains are turned off and later turned on, the modules can indicate not ready for access indefinitely when polled on their respective Peripheral Ready Register such as PRUSB register.

Workaround

None. Do not turn off power domains.

USB#04
Device sends SE0 in response to a USB bus reset

Description

The USB Device sends an Single Ended Zero (SE0) bus state (USB0DP and USB0DM driven low) in response to a USB bus reset from the Host. Per USB specification, the Device should not drive these pins in the event of a USB bus reset. This does not affect USB certification.

Workaround

None.

WDT#08
Reading the WDTVALUE register may return incorrect values when using Watchdog Timer 1

Description

Incorrect values may be read from the Watchdog Value (WDTVALUE) register at the Watchdog Timer 1 base address when using Watchdog Timer 1.

Workaround

None.

1.6 Appendix 1

To address the erratum [HIB#16 Application code may miss new tamper event during clear](#) , the HibernateTamperEventsClear() API must be replaced with the following APIs:

```
HibernateTamperEventsClearNoLock();
HibernateTamperUnlock();
HibernateTamperLock();
```

The API definitions are as follows:

```

//*****
//
//! Clears the tamper feature events without Unlock and Lock.
//!
//! This function is used to clear all tamper events without unlock/locking
//! the tamper control registers, so API HibernateTamperUnlock() should be
//! called before this function, and API HibernateTamperLock() should be
//! called after to ensure that tamper control registers are locked.
//!
//! This function doesn't block until the write is complete.
//! Therefore, care must be taken to ensure the next immediate write will
//! occur only after the write complete bit is set.
//!
//! This function is used to implement a software workaround in NMI interrupt
//! handler to fix an issue when a new tamper event could be missed during
//! the clear of current tamper event.
//!
//! \note The hibernate tamper feature is not available on all
//! devices. Please consult the data sheet for the device that you
//! are using to determine if this feature is available.
//!
//! \return None.
//
//*****
void
HibernateTamperEventsClearNoLock(void)
{
    //
    // wait for write completion.
    //
    _HibernateWriteComplete();
    //
    // Set the tamper event clear bit.
    //
    HWREG(HIB_TPCTL) |= HIB_TPCTL_TPCLR;
}
//*****
//
//! Unlock temper registers.
//!
//! This function is used to unlock the temper control registers. This
//! function should be only used before calling API
//! HibernateTamperEventsClearNoLock().
//!
//! \note The hibernate tamper feature is not available on all
//! devices. Please consult the data sheet for the device that you
//! are using to determine if this feature is available.
//!
//! \return None.
//
//*****
void
HibernateTamperUnlock(void)
{
    //
    // unlock the tamper registers.
    //
    HWREG(HIB_LOCK) = HIB_LOCK_HIBLOCK_KEY;
    _HibernateWriteComplete();
}
//*****
//
//! Lock temper registers.
//!

```

```

//! This function is used to lock the temper control registers. This
//! function should be used after calling API
//! HibernateTamperEventsClearNoLock().
//!
//! \note The hibernate tamper feature is not available on all
//! devices. Please consult the data sheet for the device that you
//! are using to determine if this feature is available.
//!
//! \return None.
//!
//! *****
void
HibernateTamperLock(void)
{
    //
    // wait for write completion.
    //
    _HibernateWriteComplete();
    //
    // Lock the tamper registers.
    //
    HWREG(HIB_LOCK) = 0;
    _HibernateWriteComplete();
}

```

The software workaround must be added in the NMI Handler. The code mainly polls the tamper log entries during the tamper clear synchronization.

An example of an NMI handler with this workaround is shown below.

```

static uint32_t g_ui32RTCLog[4];
static uint32_t g_ui32EventLog[4];
// *****
//
// Handles an NMI interrupt generated by a Tamper event.
//
// *****
void
NMITamperEventHandler(void)
{
    uint32_t ui32NMISStatus, ui32TamperStatus;
    uint32_t pui32Buf[3];
    uint8_t ui8Idx, ui8StartIdx;
    bool bDetectedEventsDuringClear;
    //
    // Get the cause of the NMI event.
    //
    ui32NMISStatus = SysCtlNMISStatus();
    //
    // we should have got the cause of the NMI event from the above function.
    // But in Snowflake RAO the NMIC register is not set correctly when an
    // event occurs. So as a work around check if the NMI event is caused by a
    // tamper event and append this to the return value from SysCtlNMISStatus().
    // This way only this section can be removed once the bug is fixed in next
    // silicon rev.
    //
    ui32TamperStatus = HibernateTamperStatusGet();
    if(ui32TamperStatus & (HIBERNATE_TAMPER_STATUS_EVENT |
        HIBERNATE_TAMPER_STATUS_EXT_OSC_FAILED))
    {
        ui32NMISStatus |= SYSCTL_NMI_TAMPER;
    }
    //
    // check if SysCtlNMISStatus() returned a valid value.
    //
    if(ui32NMISStatus)
    {
        //
        // Check if the NMI Interrupt is due to a Tamper event.
        //
        if(ui32NMISStatus & SYSCTL_NMI_TAMPER)
        {
            //
            // If the previous NMI event has not been processed by main
            // thread, we need to OR the new event along with the old ones.
            //
            if(g_ui32NMIEvent == 0)

```

```

{
    //
    // Reset variables that used for tamper event.
    //
    g_ui32TamperEventFlag = 0;
    g_ui32TamperRTCLog = 0;
    //
    // Clean the log data for debugging purpose.
    //
    memset(g_ui32RTCLog, 0, (sizeof(g_ui32RTCLog))<<2);
    memset(g_ui32EventLog, 0, (sizeof(g_ui32EventLog))<<2);
}
//
// Log the tamper event data before clearing tamper events.
//
for(ui8Idx = 0; ui8Idx < 4; ui8Idx++)
{
    if(HibernateTamperEventsGet(ui8Idx,
                                &g_ui32RTCLog[ui8Idx],
                                &g_ui32EventLog[ui8Idx]))
    {
        //
        // Event in this log entry, store it.
        //
        g_ui32TamperEventFlag |= g_ui32EventLog[ui8Idx];
        g_ui32TamperRTCLog = g_ui32RTCLog[ui8Idx];
    }
    else
    {
        //
        // No event in this log entry. Done checking the logs.
        //
        break;
    }
}
//
// Process external oscillator failed event.
//
if(ui32TamperStatus & HIBERNATE_TAMPER_STATUS_EXT_OSC_FAILED)
{
    g_ui32TamperXOSCFailEvent++;
    g_ui32TamperEventFlag |= HIBERNATE_TAMPER_EVENT_EXT_OSC;
    g_ui32TamperRTCLog = HWREG(HIB_TPLOG0);
}

```

Note

This is the beginning of the block of workaround code.

```

// The following block of code is to workaround hardware defect
// which results in missing new tamper events during tamper clear
// synchronization.
//
// There is a window after the application code writes the tamper
// clear where a new tamper event can be missed if the application
// requires more than one tamper event pins detection.
//
// The tamper clear is synchronized to the hibernate 32kHz clock
// domain. The clear takes 3 rising edges of the 32kHz clock.
// During this window, new tamper events could be missed.
// A software workaround is to poll the tamper log during the
// tamper event clear synchronization.
//
//
// Clear the flag for the case there are events triggered
// during clear execution.
//
bDetectedEventsDuringClear = false;
//
// Unlock the Tamper Control register. This is required before
// calling HibernateTamperEventsClearNoLock().
//
HibernateTamperUnlock();
do

```

```

{
    //
    // We will start to poll the log registers at index 1 for
    // any new events.
    //
    ui8StartIdx = 1;
    //
    // Clear the Tamper event.
    // Note this API doesn't wait for synchronization, which
    // allows us to check the tamper log during
    // synchronization.
    //
    HibernateTamperEventsClearNoLock();
    //
    // Check new tamper event during tamper event clear
    // synchronization.
    // This will take about 92us(three clock cycles) at most.
    //
    while(HibernateTamperStatusGet() & HIBERNATE_TAMPER_STATUS_EVENT)
    {
        //
        // Clear execution isn't done yet , poll for new events.
        // If there were any new event, it will be logged in log 1
        // registers and so on.
        //
        for(ui8Idx = ui8StartIdx; ui8Idx < 4; ui8Idx++)
        {
            if(HibernateTamperEventsGet(ui8Idx,
                                        &g_ui32RTCLog[ui8Idx],
                                        &g_ui32EventLog[ui8Idx]))
            {
                //
                // detected new event, store it.
                //
                g_ui32TamperEventFlag |= g_ui32EventLog[ui8Idx];
                //
                // check for more event.
                //
                continue;
            }
            else
            {
                //
                // no new event in this log, update the log index
                // to be checked next, and break out of loop.
                //
                ui8StartIdx = ui8Idx;
                break;
            }
        }
        //
        // all last three logs have info. Check if all 4 logs
        // have the same info. This is to detect the case that
        // events happen during clear execution.
        //
        if(ui8Idx == 4)
        {
            //
            // If events happens during clear
            // execution, all four log registers will be
            // logged with the same event, to detect this
            // condition, we will compare with all four log data.
            //
            if(HibernateTamperEventsGet(0, &g_ui32RTCLog[0], &g_ui32EventLog[0]))
            {
                if((g_ui32RTCLog[0] == g_ui32RTCLog[1]) &&
                    (g_ui32EventLog[0] == g_ui32EventLog[1]) &&
                    (g_ui32RTCLog[0] == g_ui32RTCLog[2]) &&
                    (g_ui32EventLog[0] == g_ui32EventLog[2]) &&
                    (g_ui32RTCLog[0] == g_ui32RTCLog[3]) &&
                    (g_ui32EventLog[0] == g_ui32EventLog[3]))
                {
                    //
                    // Detected events during clear execution.
                    // Event logging takes priority, the clear
                    // will not be done in this case. We will need
                    // to go back to the beginning of the loop and
                    // clear the events.
                }
            }
        }
    }
}

```



```

        //
        if(bDetectedEventsDuringClear)
        {
            //
            // This condition has already detected,
            // we have cleared the event,
            // clear the flag.
            //
            bDetectedEventsDuringClear = false;
        }
        else
        {
            // This is the first time it has been
            // detected, set the flag.
            //
            bDetectedEventsDuringClear = true;
        }
        //
        // Break out of while loop so that we can
        // clear the events, and start the
        // workaround all over again.
        //
        break;
    }
}
else
{
    //
    // Log 0 didn't detect any events. So this is not
    // the case of missing events during clear
    // execution.
    // Update the log index at which we will poll next.
    // It should be the last log entry that OR all the
    // new events.
    //
    ui8StartIdx = 3;
}
}
}
}
while(bDetectedEventsDuringClear);
//
// Lock the Tamper Control register.
//
HibernateTamperLock();

```

Note

This is the end of the block of workaround code.

```

//
// Save the tamper event and RTC log info in the Hibernate Memory
//
HibernateDataGet(pui32Buf, 3);
pui32Buf[1] = g_ui32TamperEventFlag;
pui32Buf[2] = g_ui32TamperRTCLog;
HibernateDataSet(pui32Buf, 3);
//
// Signal the main loop that an NMI event occurred.
//
g_ui32NMIEvent++;
}
//
// Clear NMI events
//
SysCtlNMIClear(ui32NMISStatus);
}
}
}

```

1.7 Appendix 2

To address the erratum [EPI#01 Data reads can be corrupted when the code address space in the EPI module is used](#), the following code should be added to the epi.h file.

```
#ifndef rvmdk
//*****
//
// Keil case.
//
//*****
inline void
EPIWorkaroundWordWrite(uint32_t *pui32Addr, uint32_t ui32Value)
{
    uint32_t ui32Scratch;
    __asm
    {
        //
        // Add a NOP to ensure we don't have a flash read immediately before
        // the EPI read.
        //
        NOP
        //
        // Perform the write we're actually interested in.
        //
        STR ui32Value, [pui32Addr]
        //
        // Read from SRAM to ensure that we don't have an EPI write followed by
        // a flash read.
        //
        LDR ui32Scratch, [__current_sp()]
    }
}

inline uint32_t
EPIWorkaroundWordRead(uint32_t *pui32Addr)
{
    uint32_t ui32Value, ui32Scratch;
    __asm
    {
        //
        // Add a NOP to ensure we don't have a flash read immediately before
        // the EPI read.
        //
        NOP
        //
        // Perform the read we're actually interested in.
        //
        LDR ui32Value, [pui32Addr]
        //
        // Read from SRAM to ensure that we don't have an EPI read followed by
        // a flash read.
        //
        LDR ui32Scratch, [__current_sp()]
    }
    return(ui32Value);
}

inline void
EPIWorkaroundHwordWrite(uint16_t *pui16Addr, uint16_t ui16Value)
{
    uint32_t ui32Scratch;
    __asm
    {
        //
        // Add a NOP to ensure we don't have a flash read immediately before
        // the EPI read.
        //
        NOP
        //
        // Perform the write we're actually interested in.
        //
        STRH ui16Value, [pui16Addr]
        //
        // Read from SRAM to ensure that we don't have an EPI write followed by
        // a flash read.
        //
        LDR ui32Scratch, [__current_sp()]
    }
}
```

```

}
inline uint16_t
EPIWorkaroundHWordRead(uint16_t *pui16Addr)
{
    uint32_t ui32Scratch;
    uint16_t ui16Value;
    __asm
    {
        //
        // Add a NOP to ensure we don't have a flash read immediately before
        // the EPI read.
        //
        NOP
        //
        // Perform the read we're actually interested in.
        //
        LDRH ui16Value, [pui16Addr]
        //
        // Read from SRAM to ensure that we don't have an EPI read followed by
        // a flash read.
        //
        LDR ui32Scratch, [__current_sp()]
    }
    return(ui16Value);
}
inline void
EPIWorkaroundByteWrite(uint8_t *pui8Addr, uint8_t ui8Value)
{
    uint32_t ui32Scratch;
    __asm
    {
        //
        // Add a NOP to ensure we don't have a flash read immediately before
        // the EPI read.
        //
        NOP
        //
        // Perform the write we're actually interested in.
        //
        STRB ui8Value, [pui8Addr]
        //
        // Read from SRAM to ensure that we don't have an EPI write followed by
        // a flash read.
        //
        LDR ui32Scratch, [__current_sp()]
    }
}
inline uint8_t
EPIWorkaroundByteRead(uint8_t *pui8Addr)
{
    uint32_t ui32Scratch;
    uint8_t ui8Value;
    __asm
    {
        //
        // Add a NOP to ensure we don't have a flash read immediately before
        // the EPI read.
        //
        NOP
        //
        // Perform the read we're actually interested in.
        //
        LDRB ui8Value, [pui8Addr]
        //
        // Read from SRAM to ensure that we don't have an EPI read followed by
        // a flash read.
        //
        LDR ui32Scratch, [__current_sp()]
    }
    return(ui8Value);
}
#else
#ifdef ccs
//*****
//
// Code Composer Studio versions of these functions can be found in separate
// source file epi_workaround_ccs.s.
//
//

```

```

//*****
extern void EPIWorkaroundWordWrite(uint32_t *pui32Addr, uint32_t ui32Value);
extern uint32_t EPIWorkaroundWordRead(uint32_t *pui32Addr);
extern void EPIWorkaroundHWordWrite(uint16_t *pui16Addr, uint16_t ui16Value);
extern uint16_t EPIWorkaroundHWordRead(uint16_t *pui16Addr);
extern void EPIWorkaroundByteWrite(uint8_t *pui8Addr, uint8_t ui8Value);
extern uint8_t EPIWorkaroundByteRead(uint8_t *pui8Addr);
#else
//*****
//
// GCC and IAR case.
//
//*****
inline void
EPIWorkaroundWordWrite(uint32_t *pui32Addr, uint32_t ui32Value)
{
    volatile register uint32_t ui32Scratch;
    __asm volatile (
        //
        // Add a NOP to ensure we don't have a flash read immediately before
        // the EPI read.
        //
        "    NOP\n"
        "    STR %[value],[%[addr]]\n"
        "    LDR %[scratch],[sp]\n"
        : [scratch] "=r" (ui32Scratch)
        : [addr] "r" (pui32Addr), [value] "r" (ui32Value)
    );
    //
    // Keep the compiler from generating a warning.
    //
    ui32Scratch = ui32Scratch;
}
inline uint32_t
EPIWorkaroundWordRead(uint32_t *pui32Addr)
{
    volatile register uint32_t ui32Data, ui32Scratch;
    //
    // ui32Scratch is not used other than to add a padding read following the
    // "real" read.
    //
    __asm volatile(
        //
        // Add a NOP to ensure we don't have a flash read immediately before
        // the EPI read.
        //
        "    NOP\n"
        "    LDR %[ret],[%[addr]]\n"
        "    LDR %[scratch],[sp]\n"
        : [ret] "=r" (ui32Data),
          [scratch] "=r" (ui32Scratch)
        : [addr] "r" (pui32Addr)
    );
    //
    // Keep the compiler from generating a warning.
    //
    ui32Scratch = ui32Scratch;
    return(ui32Data);
}
inline void
EPIWorkaroundHWordWrite(uint16_t *pui16Addr, uint16_t ui16Value)
{
    volatile register uint32_t ui32Scratch;
    __asm volatile (
        //
        // Add a NOP to ensure we don't have a flash read immediately before
        // the EPI read.
        //
        "    NOP\n"
        "    STRH %[value],[%[addr]]\n"
        "    LDR %[scratch],[sp]\n"
        : [scratch] "=r" (ui32Scratch)
        : [addr] "r" (pui16Addr), [value] "r" (ui16Value)
    );
    //
    // Keep the compiler from generating a warning.
    //
    ui32Scratch = ui32Scratch;
}

```

```

}
inline uint16_t
EPIWorkaroundHWordRead(uint16_t *pui16Addr)
{
    register uint16_t ui16Data;
    register uint32_t ui32Scratch;
    //
    // ui32Scratch is not used other than to add a padding read following the
    // "real" read.
    //
    __asm volatile(
        //
        // Add a NOP to ensure we don't have a flash read immediately before
        // the EPI read.
        //
        "    NOP\n"
        "    LDRH %[ret],[%[addr]]\n"
        "    LDR %[scratch],[sp]\n"
        : [ret] "=r" (ui16Data),
          [scratch] "=r" (ui32Scratch)
        : [addr] "r" (pui16Addr)
    );
    //
    // Keep the compiler from generating a warning.
    //
    ui32Scratch = ui32Scratch;
    return(ui16Data);
}
inline void
EPIWorkaroundByteWrite(uint8_t *pui8Addr, uint8_t ui8Value)
{
    volatile register uint32_t ui32Scratch;
    __asm volatile (
        //
        // Add a NOP to ensure we don't have a flash read immediately before
        // the EPI read.
        //
        "    NOP\n"
        "    STRB %[value],[%[addr]]\n"
        "    LDR %[scratch],[sp]\n"
        : [scratch] "=r" (ui32Scratch)
        : [addr] "r" (pui8Addr), [value] "r" (ui8Value)
    );
    //
    // Keep the compiler from generating a warning.
    //
    ui32Scratch = ui32Scratch;
}
inline uint8_t
EPIWorkaroundByteRead(uint8_t *pui8Addr)
{
    register uint8_t ui8Data;
    register uint32_t ui32Scratch;
    //
    // ui32Scratch is not used other than to add a padding read following the
    // "real" read.
    //
    __asm volatile(
        //
        // Add a NOP to ensure we don't have a flash read immediately before
        // the EPI read.
        //
        "    NOP\n"
        "    LDRB %[ret],[%[addr]]\n"
        "    LDR %[scratch],[sp]\n"
        : [ret] "=r" (ui8Data),
          [scratch] "=r" (ui32Scratch)
        : [addr] "r" (pui8Addr)
    );
    //
    // Keep the compiler from generating a warning.
    //
    ui32Scratch = ui32Scratch;
    return(ui8Data);
}
#endif

```

In addition, if using CCS, the following code should be saved as a file entitled `epi_workaround_ccs.s` *driverlib* directory and included in the project:

```

*****
;
; epi_workaround_ccs.s - EPI memory access functions.
;
; Copyright (c) 2013 Texas Instruments Incorporated. All rights reserved.
; TI Information - Selective Disclosure
;
*****
*****
; void EPIWorkaroundWordWrite(uint32_t *pui32Addr, uint32_t ui32Value)
;
*****
    .sect ".text:EPIWorkaroundWordWrite"
    .global EPIWorkaroundWordWrite
EPIWorkaroundWordWrite:
    ;
    ; Include a no-op to ensure that we don't have a flash data access
    ; immediately before the EPI access.
    ;
    nop
    ;
    ; Store the word in EPI memory.
    ;
    str r1, [r0]
    ;
    ; Make a dummy read from the stack to ensure that we don't have a flash
    ; data access immediately after the EPI access.
    ;
    ldr r1, [sp]
    ;
    ; Return to the caller.
    ;
    bx lr
    .align 4
*****
;
; uint32_t EPIWorkaroundWordRead(uint32_t *pui32Addr)
;
*****
    .sect ".text:EPIWorkaroundWordRead"
    .global EPIWorkaroundWordRead
EPIWorkaroundWordRead:
    ;
    ; Include a no-op to ensure that we don't have a flash data access
    ; immediately before the EPI access.
    ;
    nop
    ;
    ; Read the word from EPI memory.
    ;
    ldr r0, [r0]
    ;
    ; Make a dummy read from the stack to ensure that we don't have a flash
    ; data access immediately after the EPI access.
    ;
    ldr r1, [r13]
    ;
    ; Return to the caller.
    ;
    bx lr
    .align 4
*****
;
; void EPIWorkaroundHWordWrite(uint16_t *pui16Addr, uint16_t ui16Value)
;
*****
    .sect ".text:EPIWorkaroundHWordWrite"
    .global EPIWorkaroundHWordWrite
EPIWorkaroundHWordWrite:
    ;
    ; Include a no-op to ensure that we don't have a flash data access
    ; immediately before the EPI access.
    ;

```

```

    nop
    ;
    ; Store the word in EPI memory.
    ;
    strh r1, [r0]
    ;
    ; Make a dummy read from the stack to ensure that we don't have a flash
    ; data access immediately after the EPI access.
    ;
    ldr r1, [sp]
    ;
    ; Return to the caller.
    ;
    bx lr
    .align 4
;*****
;
; uint16_t EPIWorkaroundHWordRead(uint16_t *pui16Addr)
;
;*****
    .sect ".text:EPIWorkaroundHWordRead"
    .global EPIWorkaroundHWordRead
EPIWorkaroundHWordRead:
    ;
    ; Include a no-op to ensure that we don't have a flash data access
    ; immediately before the EPI access.
    ;
    nop
    ;
    ; Read the half word from EPI memory.
    ;
    ldrh r0, [r0]
    ;
    ; Make a dummy read from the stack to ensure that we don't have a flash
    ; data access immediately after the EPI access.
    ;
    ldr r1, [r13]
    ;
    ; Return to the caller.
    ;
    bx lr
    .align 4
;*****
;
; void EPIWorkaroundByteWrite(uint8_t *pui8Addr, uint8_t ui8Value)
;
;*****
    .sect ".text:EPIWorkaroundByteWrite"
    .global EPIWorkaroundByteWrite
EPIWorkaroundByteWrite:
    ;
    ; Include a no-op to ensure that we don't have a flash data access
    ; immediately before the EPI access.
    ;
    nop
    ;
    ; Store the byte in EPI memory.
    ;
    strb r1, [r0]
    ;
    ; Make a dummy read from the stack to ensure that we don't have a flash
    ; data access immediately after the EPI access.
    ;
    ldr r1, [sp]
    ;
    ; Return to the caller.
    ;
    bx lr
    .align 4
;*****
;
; uint8_t EPIWorkaroundByteRead(uint8_t *pui8Addr)
;
;*****
    .sect ".text:EPIWorkaroundByteRead"
    .global EPIWorkaroundByteRead
EPIWorkaroundByteRead:
    ;

```

```

; Include a no-op to ensure that we don't have a flash data access
; immediately before the EPI access.
;
nop
;
; Read the byte from EPI memory.
ldrb r0, [r0]
;
; Make a dummy read from the stack to ensure that we don't have a flash
; data access immediately after the EPI access.
;
ldr r1, [r13]
;
; Return to the caller.
;
bx lr
.align 4
.end

```

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3 Revision History

Changes from October 1, 2017 to June 30, 2025 (from Revision * (October 2017) to Revision A (June 2025))

Page

- Added SYSCTL#24 advisory..... [12](#)

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